

CD4528BM/CD4528BC Dual Monostable Multivibrator

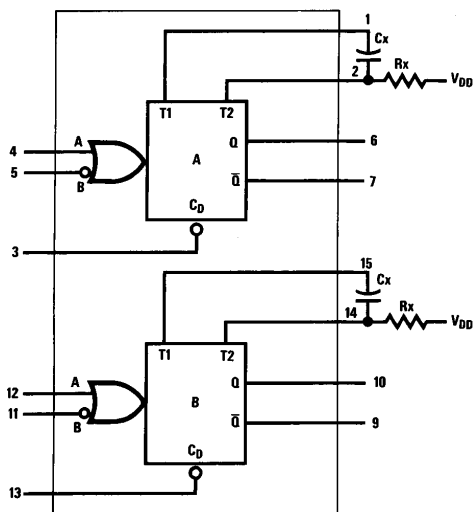
General Description

The CD4528B is a dual monostable multivibrator. Each device is retriggerable and resettable. Triggering can occur from either the rising or falling edge of an input pulse, resulting in an output pulse over a wide range of widths. Pulse duration and accuracy are determined by external timing components Rx and Cx.

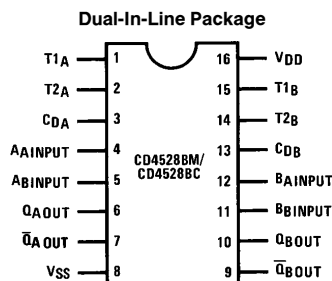
Features

- Wide supply voltage range 3.0V to 18V
- Separate reset available
- Quiescent current = 5.0 nA/package (typ.) at 5.0 V_{DC}
- Diode protection on all inputs
- Triggerable from leading or trailing edge pulse
- Capable of driving two low-power TTL loads or one low-power Schottky TTL load over the rated temperature range

Connection Diagrams



TL/F/5998-1



TL/F/5998-2

Top View
Order Number CD4528B

Truth Table

Inputs			Outputs	
Clear	A	B	Q	Q
L	X	X	L	H
X	H	X	L	H
X	X	L	L	H
H	L	↓	⌊	⌊
H	↑	H	⌊	⌊

H = High Level
L = Low Level
↑ = Transition from Low to High
↓ = Transition from High to Low
⌊ = One High Level Pulse
⌋ = One Low Level Pulse
X = Irrelevant

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V_{DD}) $-0.5 V_{DC}$ to $+18 V_{DC}$

Input Voltage, All Inputs (V_{IN}) $-0.5 V_{DC}$ to $V_{DD} + 0.5 V_{DC}$

Storage Temperature Range (T_S) -65°C to $+150^{\circ}\text{C}$

Power Dissipation (P_D)

Dual-In-Line 700 mW

Small Outline 500 mW

Lead Temperature (T_L)
(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3V to 15V

Input Voltage (V_{IN}) 0V to V_{DD}

Operating Temperature Range (T_A) -55°C to $+125^{\circ}\text{C}$

CD4528BM -40°C to $+85^{\circ}\text{C}$

CD4528BC

DC Electrical Characteristics CD4528BM (Note 2)

Symbol	Parameter	Conditions	-55°C		$+25^{\circ}\text{C}$			$+125^{\circ}\text{C}$		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5\text{V}$		5	0.005		5		150	μA
		$V_{DD} = 10\text{V}$		10	0.010		10		300	μA
		$V_{DD} = 15\text{V}$		20	0.015		20		600	μA
V_{OL}	Low Level Output Voltage	$V_{DD} = 5\text{V}$		0.05			0.05		0.05	V
		$V_{DD} = 10\text{V}$		0.05			0.05		0.05	V
		$V_{DD} = 15\text{V}$		0.05			0.05		0.05	V
V_{OH}	High Level Output Voltage	$V_{DD} = 5\text{V}$	4.95		4.95	5.0		4.95		V
		$V_{DD} = 10\text{V}$	9.95		9.95	10.0		9.95		V
		$V_{DD} = 15\text{V}$	14.95		14.95	15.0		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5\text{V}, V_O = 0.5\text{V}$ or 4.5V		1.5		2.25	1.5		1.5	V
		$V_{DD} = 10\text{V}, V_O = 1\text{V}$ or 9V		3.0		4.50	3.0		3.0	V
		$V_{DD} = 15\text{V}, V_O = 1.5\text{V}$ or 13.5V		4.0		6.75	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5\text{V}, V_O = 0.5\text{V}$ or 4.5V	3.5		3.5	2.75		3.5		V
		$V_{DD} = 10\text{V}, V_O = 1\text{V}$ or 9V	7.0		7.0	5.50		7.0		V
		$V_{DD} = 15\text{V}, V_O = 1.5\text{V}$ or 13.5V	11.0		11.0	8.25		11.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5\text{V}, V_O = 0.4\text{V}$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10\text{V}, V_O = 0.5\text{V}$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15\text{V}, V_O = 1.5\text{V}$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5\text{V}, V_O = 4.6\text{V}$	-0.25		-0.2	-0.36		-0.14		mA
		$V_{DD} = 10\text{V}, V_O = 9.5\text{V}$	-0.62		-0.5	-0.9		-0.35		mA
		$V_{DD} = 15\text{V}, V_O = 13.5\text{V}$	-1.8		-1.5	-3.5		-1.1		mA
I_{IN}	Input Current	$V_{DD} = 15\text{V}, V_{IN} = 0\text{V}$		-0.1		-10^{-5}	-0.1		-1.0	μA
		$V_{DD} = 15\text{V}, V_{IN} = 15\text{V}$		0.1		10^{-5}	0.1		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range", they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: $V_{SS} = 0\text{V}$ unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

DC Electrical Characteristics CD4528BC (Note 2)

Symbol	Parameter	Conditions	− 40°C		+ 25°C			+ 85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I _{DD}	Quiescent Device Current	V _{DD} = 5V		20		0.005	20		150	μA
		V _{DD} = 10V		40		0.010	40		300	μA
		V _{DD} = 15V		80		0.015	80		600	μA
V _{OL}	Low Level Output Voltage	V _{DD} = 5V		0.05			0.05		0.05	V
		V _{DD} = 10V		0.05			0.05		0.05	V
		V _{DD} = 15V		0.05			0.05		0.05	V
V _{OH}	High Level Output Voltage	V _{DD} = 5V	4.95		4.95	5.0		4.95		V
		V _{DD} = 10V	9.95		9.95	10.0		9.95		V
		V _{DD} = 15V	14.95		14.95	15.0		14.95		V
V _{IL}	Low Level Input Voltage	V _{DD} = 5V, V _O = 0.5V or 4.5V		1.5		2.25	1.5		1.5	V
		V _{DD} = 10V, V _O = 1V or 9V		3.0		4.50	3.0		3.0	V
		V _{DD} = 15V, V _O = 1.5V or 13.5V		4.0		6.75	4.0		4.0	V
V _{IH}	High Level Input Voltage	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
		V _{DD} = 10V, V _O = 1V or 9V	7.0		7.0	5.50		7.0		V
		V _{DD} = 15V, V _O = 1.5V or 13.5V	11.0		11.0	8.25		11.0		V
I _{OL}	Low Level Output Current (Note 3)	V _{DD} = 5V, V _O = 0.4V	0.52		0.44	0.88		0.36		mA
		V _{DD} = 10V, V _O = 0.5V	1.3		1.1	2.25		0.9		mA
		V _{DD} = 15V, V _O = 1.5V	3.6		3.0	8.8		2.4		mA
I _{OH}	High Level Output Current (Note 3)	V _{DD} = 5V, V _O = 4.6V	−0.2		−0.16	−0.36		−0.12		mA
		V _{DD} = 10V, V _O = 9.5V	−0.5		−0.4	−0.9		−0.3		mA
		V _{DD} = 15V, V _O = 13.5V	−1.4		−1.2	−3.5		−1.0		mA
I _{IN}	Input Current	V _{DD} = 15V, V _{IN} = 0V		−0.3		−10 ^{−5}	−0.3		−1.0	μA
		V _{DD} = 15V, V _{IN} = 15V		0.3		10 ^{−5}	0.3		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range", they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

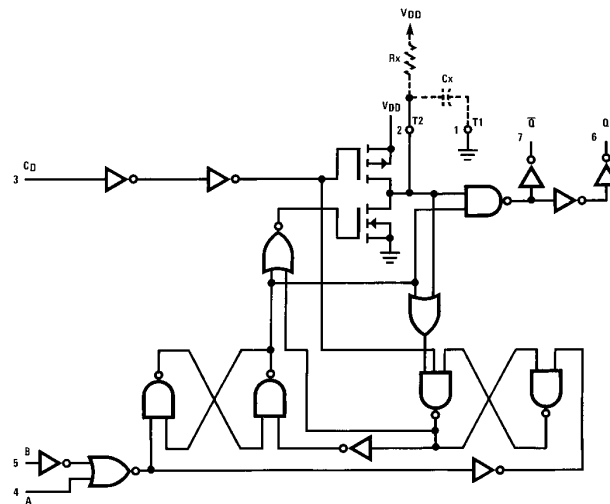
AC Electrical Characteristics* CD4528BM

$T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$, Input $t_r = t_f = 20\text{ ns}$, unless otherwise specified

Parameter	Conditions	Min	Typ	Max	Units
Output Rise Time	$t_r = (3.0\text{ ns/pF}) C_L + 30\text{ ns}$, $V_{DD} = 5.0\text{V}$		180	400	ns
	$t_r = (1.5\text{ ns/pF}) C_L + 15\text{ ns}$, $V_{DD} = 10.0\text{V}$		90	200	ns
	$t_r = (1.1\text{ ns/pF}) C_L + 10\text{ ns}$, $V_{DD} = 15.0\text{V}$		65	160	ns
Output Fall Time	$t_f = (1.5\text{ ns/pF}) C_L + 25\text{ ns}$, $V_{DD} = 5.0\text{V}$		100	200	ns
	$t_f = (0.75\text{ ns/pF}) C_L + 12.5\text{ ns}$, $V_{DD} = 10\text{V}$		50	100	ns
	$t_f = (0.55\text{ ns/pF}) C_L + 9.5\text{ ns}$, $V_{DD} = 15.0\text{V}$		35	80	ns
Turn-Off, Turn-On Delay A or B to Q or $\bar{Q}$ $C_x = 15\text{ pF}$, $R_x = 5.0\text{ k}\Omega$	$t_{PLH}, t_{PHL} = (1.7\text{ ns/pF}) C_L + 240\text{ ns}$, $V_{DD} = 5.0\text{V}$		230	500	ns
	$t_{PLH}, t_{PHL} = (0.66\text{ ns/pF}) C_L + 8\text{ ns}$, $V_{DD} = 10.0\text{V}$		100	250	ns
	$t_{PLH}, t_{PHL} = (0.5\text{ ns/pF}) C_L + 65\text{ ns}$, $V_{DD} = 15.0\text{V}$		65	150	ns
Turn-Off, Turn-On Delay A or B to Q or $\bar{Q}$ $C_x = 100\text{ pF}$, $R_x = 10\text{ k}\Omega$	$t_{PLH}, t_{PHL} = (1.7\text{ ns/pF}) C_L + 620\text{ ns}$, $V_{DD} = 5.0\text{V}$		230	500	ns
	$t_{PLH}, t_{PHL} = (0.66\text{ ns/pF}) C_L + 257\text{ ns}$, $V_{DD} = 10.0\text{V}$		100	250	ns
	$t_{PLH}, t_{PHL} = (0.5\text{ ns/pF}) C_L + 185\text{ ns}$, $V_{DD} = 15.0\text{V}$		65	150	ns
Minimum Input Pulse Width A or B $C_x = 15\text{ pF}$, $R_x = 5.0\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		60	150	ns
	$V_{DD} = 10.0\text{V}$		20	50	ns
	$V_{DD} = 15\text{V}$		20	50	ns
$C_x = 1000\text{ pF}$, $R_x = 10\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		60	150	ns
	$V_{DD} = 10.0\text{V}$		20	50	ns
	$V_{DD} = 15.0\text{V}$		20	50	ns
Output Pulse Width Q or $\bar{Q}$ For $C_x < 0.01\text{ }\mu\text{F}$ (See Graph for Appropriate V_{DD} Level) $C_x = 15\text{ pF}$, $R_x = 5.0\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		550		ns
	$V_{DD} = 10.0\text{V}$		350		ns
	$V_{DD} = 15.0\text{V}$		300		ns
For $C_x > 0.01\text{ }\mu\text{F}$ Use $PW_{out} = 0.2 R_x C_x \ln [V_{DD} - V_{SS}]$ $C_x = 10,000\text{ pF}$, $R_x = 10\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$	15	29	45	μs
	$V_{DD} = 10.0\text{V}$	10	37	90	μs
	$V_{DD} = 15.0\text{V}$	15	42	95	μs
Pulse Width Match between Circuits in the Same Package $C_x = 10,000\text{ pF}$, $R_x = 10\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		6	25	%
	$V_{DD} = 10.0\text{V}$		8	35	%
	$V_{DD} = 15.0\text{V}$		8	35	%
Reset Propagation Delay, t_{PLH}, t_{PHL} $C_x = 15\text{ pF}$, $R_x = 5.0\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		325	600	ns
	$V_{DD} = 10.0\text{V}$		90	225	ns
	$V_{DD} = 15.0\text{V}$		60	170	ns
$C_x = 1000\text{ pF}$, $R_x = 10\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		7.0		μs
	$V_{DD} = 10.0\text{V}$		6.7		μs
	$V_{DD} = 15.0\text{V}$		6.7		μs
Minimum Retrigger Time $C_x = 15\text{ pF}$, $R_x = 5.0\text{ k}\Omega$ $C_x = 1000\text{ pF}$, $R_x = 10\text{ k}\Omega$	$V_{DD} = 5.0\text{V}$		0		ns
	$V_{DD} = 10.0\text{V}$		0		ns
	$V_{DD} = 15.0\text{V}$		0		ns
	$V_{DD} = 5.0\text{V}$		0		ns
	$V_{DD} = 10.0\text{V}$		0		ns
	$V_{DD} = 15.0\text{V}$		0		ns

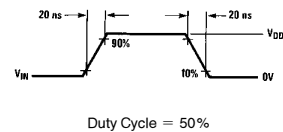
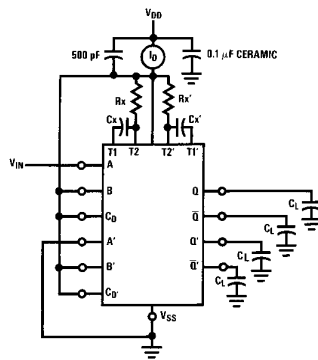
*AC parameters are guaranteed by DC correlated testing.

Logic Diagrams (1/2 of Device Shown)



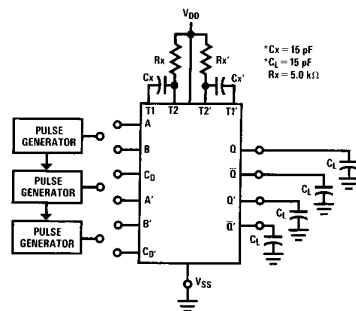
Note: Externally ground pins 1 and 15 to pin 8.

TL/F/5998-3



TL/F/5998-10

FIGURE 1. Power Dissipation Test Circuit and Waveforms



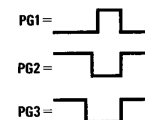
TL/F/5998-5

Input Connections

Characteristics	C_D	A	B
t_{PLH} , t_{PHL} , t_r , t_f , PW_{out} , PW_{in}	V_{DD}	PG1	V_{DD}
t_{PLH} , t_{PHL} , t_r , t_f , PW_{out} , PW_{in}	V_{DD}	V_{SS}	PG2
$t_{PLH(R)}$, $t_{PHL(R)}$, PW_{in}	PG3	PG1	PG2

*Includes capacitance of probes, wiring, and fixture parasitic.

Note: AC test waveforms for PG1, PG2, and PG3 on next page.



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FIGURE 2. AC Test Circuit

Logic Diagrams (1/2 of Device Shown) (Continued)

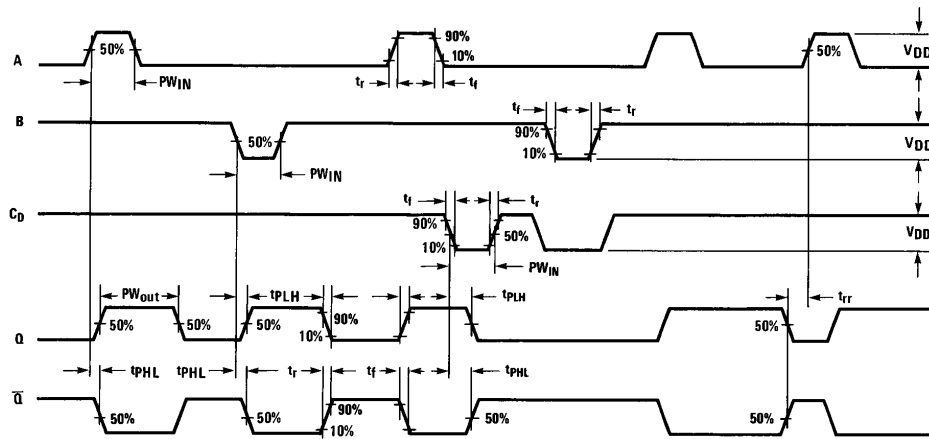


FIGURE 3. AC Test Waveforms

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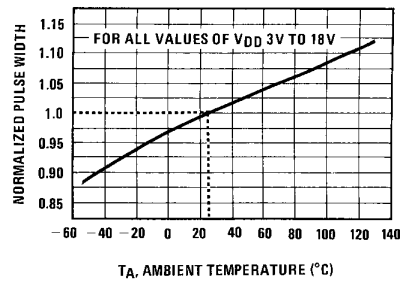


FIGURE 4. Normalized Pulse Width vs Temperature

TL/F/5998-8

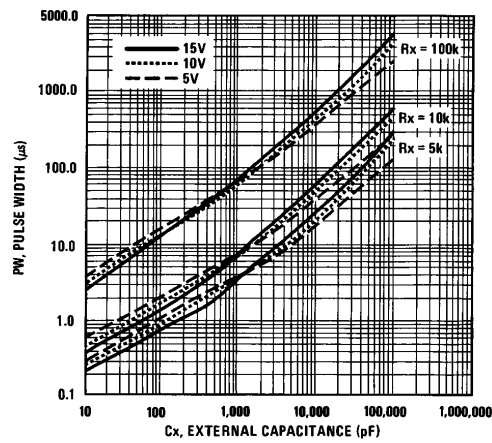


FIGURE 5. Pulse Width vs C_x

TL/F/5998-9

The drawing illustrates the mechanical specifications of the J16A package. The top view shows a rectangular body with pins on all four sides. Key dimensions include a total width of 0.785" [19.94] MAX, a pin pitch of 0.037" ± 0.005 TYP, and a pin diameter of 0.025" [0.64]. The side view shows a height of 0.220"-0.310" [5.59-7.87] and a lead height of 0.005"-0.020" TYP [0.13-0.51]. The detail view shows the lead profile with a 90° ± 4° angle and a lead thickness of 0.010" ± 0.002 [0.25 ± 0.05].

Top View Dimensions:

- Overall Width: 0.785" [19.94] MAX
- Pin Pitch: 0.037" ± 0.005 TYP [0.94 ± 0.13]
- Pin Diameter: R 0.025 [0.64]
- Pin Spacing: 0.055" ± 0.005 TYP [1.40 ± 0.13]
- Pin Length: 0.020"-0.060" TYP [0.51-1.52]
- Pin Thickness: 0.150" [3.81] MIN TYP
- Pin Angle: 90° ± 4° TYP
- Pin Spacing (Bottom): 0.018" ± 0.003 TYP [0.46 ± 0.08]

Side View Dimensions:

- Overall Height: 0.220"-0.310" [5.59-7.87]
- Lead Height: R 0.005-0.020 TYP [0.13-0.51]

Detail View Dimensions:

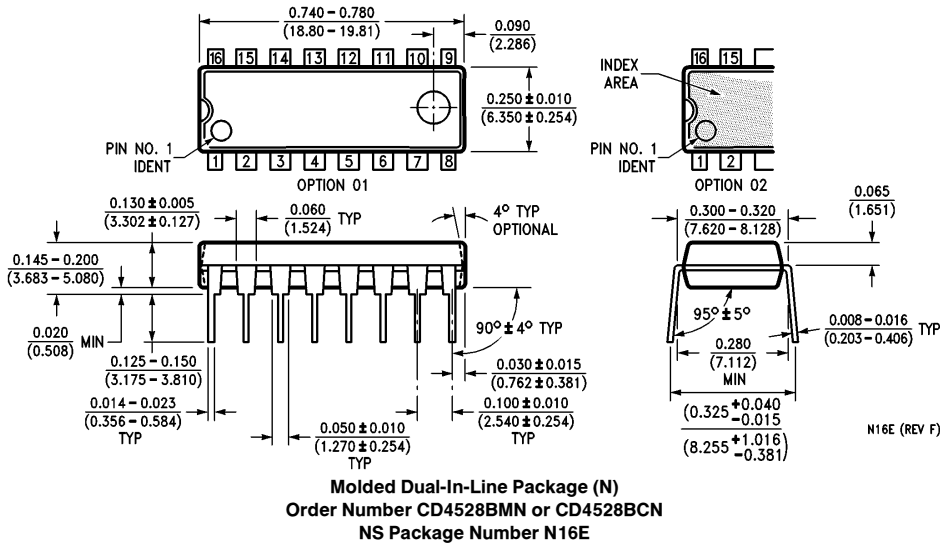
- Lead Thickness: 0.010" ± 0.002 [0.25 ± 0.05]
- Lead Angle: 95° ± 5° TYP
- Lead Spacing: 0.310"-0.410" [7.87-10.41]
- Lead Width: 0.180" [4.57] MAX
- Lead Height: 0.290"-0.320" [7.37-8.13]
- Glass Sealant

Other Dimensions:

- Pin Length (Top): 0.200" [5.08] MAX TYP
- Pin Length (Bottom): 0.125"-0.200" TYP [3.18-5.08]
- Pin Thickness (Both Ends): 0.080" [2.03] MAX
- Pin Thickness (Both Ends): 0.100" ± 0.010 TYP [2.54 ± 0.25]

J16A (REV L)

J16A (REV L)

Physical Dimensions inches (millimeters) (Continued)**LIFE SUPPORT POLICY**

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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